

L660/910-04A

Bi-Color LED for Medical Analysis

Bi-color LED of L660/910-04A consists of AlGaAs mounted on a lead frame with a clear lens. On forward bias it emits 660nm and 910nm as peak wavelength with anode common.

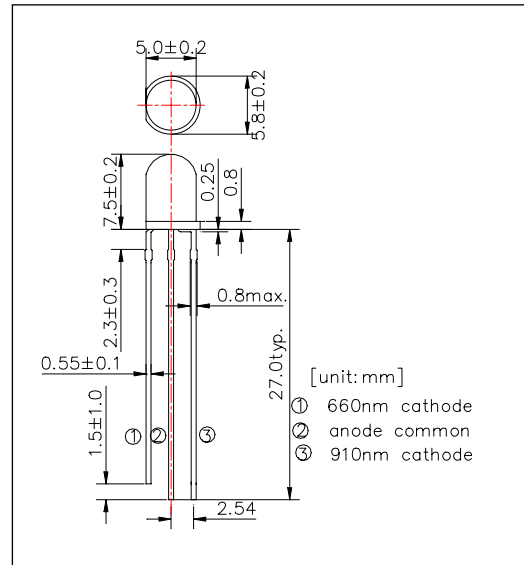
<Features>

- High Reliability
- High Power
- Anode Common

<Specifications>

1. Product Name: Bi-color LED
2. Type Number: L660/910-04A
3. Chip:
 - Chip material: AlGaAs(sub-peak free)
 - Peak Wavelength: 660nm and 910nm typ.
4. Package
 - Type: $\Phi 5$ mm clear molding
 - Resin Material: Epoxy Resin
 - Lead Frame: Soldered(Lead Free)

Outer Dimension (Unit:mm)



Absolute Maximum Ratings					
Item	Symbol	Maximum Rated Value		Unit	Ambient Temperature
		660nm	910nm		
Power Dissipation	PD	75	160	mW	Ta=25°C
Forward Current	IF	30	100	mA	Ta=25°C
Reverse Voltage	IR	10		V	Ta=25°C
Operating Temperature	TOPR	-30 ~ +85		°C	
Storage Temperature	TSTG	-30 ~ +100		°C	
Soldering Temperature	TSOL	260		°C	

Soldering condition: Soldering condition must be completed within 3 seconds at 260°C

Electro-Optical Characteristics [Ta=25°C]									
Item	Symbol	Condition	Minimum		Typical		Maximum		Unit
			660	910	660	910	660	910	
Forward Voltage	VF	IF=20mA			1.90	1.30	2.20	1.50	V
Reverse Current	IR	VR=5V					10		uA
Total Radiated Power	PO	IF=20mA	2.5	1.5	4.5	2.5			mW
Peak Wavelength	λP	IF=20mA	650	900	660	910	670	930	nm
Half Width	$\Delta \lambda$	IF=20mA			20	60			nm
Viewing Half Angle	$\theta 1/2$	IF=20mA			± 20				Deg.

Total Radiated Power is measured by Photodyne #500.
Radiant Intensity is measured by Tektronix J-6512

